MOSFETs Silicon P-Channel MOS (U-MOSⅥ)

TJ15S10M3

1. Applications

- Switching Voltage Regulators
- Motor Drivers

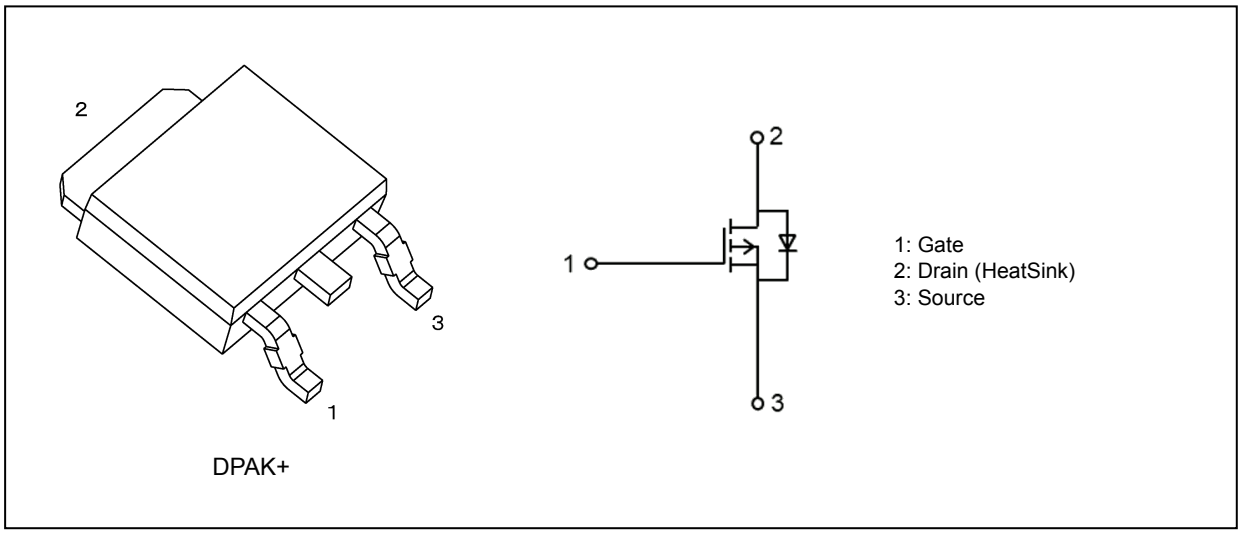
2. Features

(1) Low drain-source on-resistance: $R_{DS(ON)}$ = 100 mΩ (typ.) (V_{GS} = -10 V)

(2) Low leakage current: I_{DSS} = -10 μA (max) (V_{DS} = -100 V)

(3) Enhancement mode: V_{th} = -2.0 to -4.0 V (V_{DS} = -10 V, I_D = -1 mA)

3. Packaging and Internal Circuit



DPAK+

4. Absolute Maximum Ratings (Note) (T_a = 25 °C unless otherwise specified)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	-100	V
Gate-source voltage		V_{GSS}	-20/+10	V
Drain current (DC)	(Note 1)	I_D	-15	A
Drain current (pulsed)	(Note 1)	I_{DP}	-30	A
Power dissipation	(T_c = 25°C)	P_D	75	W
Single-pulse avalanche energy	(Note 2)	E_{AS}	29.3	mJ
Avalanche current		I_{AR}	-15	A
Channel temperature	(Note 3)	T_{ch}	175	°C
Storage temperature	(Note 3)	T_{stg}	-55 to 175	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production
2013-12

5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	$R_{th(ch-c)}$	2.0	°C/W

Note 1: Ensure that the channel temperature does not exceed 175 °C.
Note 2: V_{DD} = -25 V, T_{ch} = 25 °C (initial), L = 210 μH, R_G = 25 Ω, I_{AR} = -15 A
Note 3: The definitions of the absolute maximum channel and storage temperatures are based on AEC-Q101.

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

6. Electrical Characteristics

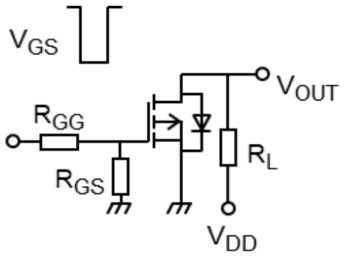
6.1. Static Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	I_{GSS}	V_{GS} = -20/+10 V, V_{DS} = 0 V	—	—	±1	μA
Drain cut-off current	I_{DSS}	V_{DS} = -100 V, V_{GS} = 0 V	—	—	-10	μA
Drain-source breakdown voltage	$V_{(BR)DSS}$	I_D = -10 mA, V_{GS} = 0 V	-100	—	—	V
Drain-source breakdown voltage (Note 4)	$V_{(BR)DSX}$	I_D = -10 mA, V_{GS} = 10 V	-75	—	—	
Gate threshold voltage	V_{th}	V_{DS} = -10 V, I_D = -1 mA	-2.0	—	-4.0	
Drain-source on-resistance	$R_{DS(ON)}$	V_{GS} = -10 V, I_D = -7.5 A	—	100	130	mΩ

Note 4: If a reverse bias is applied between gate and source, this device enters $V_{(BR)DSX}$ mode. Note that the drain-source breakdown voltage is lowered in this mode.

6.2. Dynamic Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input capacitance	C_{iss}	V_{DS} = -10 V, V_{GS} = 0 V, f = 1 MHz	—	3200	—	pF
Reverse transfer capacitance	C_{rss}		—	135	—	
Output capacitance	C_{oss}		—	190	—	
Switching time (rise time)	t_r	See Fig. 6.2.1.	—	12	—	ns
Switching time (turn-on time)	t_{on}		—	28	—	
Switching time (fall time)	t_f		—	41	—	
Switching time (turn-off time)	t_{off}		—	290	—	



V_{DD} ≈ -50 V
V_{GS} = 0 V/-10 V
I_D = -7.5 A
R_L = 6.67 Ω
R_{GG} = R_{GS} = 4.7 Ω
Duty ≤ 1 %, t_w = 10 μs

Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Q_g	V_{DD} ≈ -80 V, V_{GS} = -10 V, I_D = -15 A	—	69	—	nC
Gate-source charge 1	Q_{gs1}		—	9.4	—	nC
Gate-drain charge	Q_{gd}		—	20	—	nC

6.4. Source-Drain Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Reverse drain current (DC) (Note 5)	I_{DR}	—	—	—	-15	A
Reverse drain current (pulsed) (Note 5)	I_{DRP}	—	—	—	-30	A
Diode forward voltage	V_{DSF}	I_{DR} = -15 A, V_{GS} = 0 V	—	—	1.4	V
Reverse recovery time	t_{rr}	I_{DR} = -15 A, V_{GS} = 0 V, dI_{DR}/dt = 50 A/μs	—	70	—	ns
Reverse recovery charge	Q_{rr}		—	95	—	nC

Note 5: Ensure that the channel temperature does not exceed 175 °C.

7. Marking (Note)

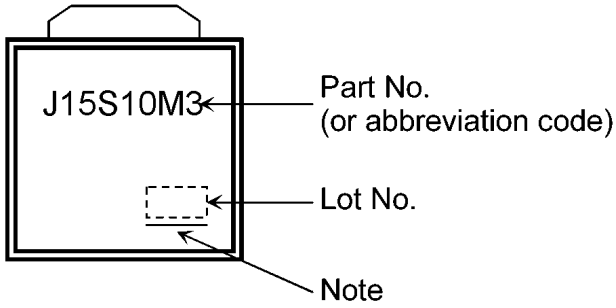


Fig. 7.1 Marking

Note: A line under a Lot No. identifies the indication of product Labels.
Not underlined: [[Pb]]/INCLUDES > MCV
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.
The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

8. Characteristics Curves (Note)

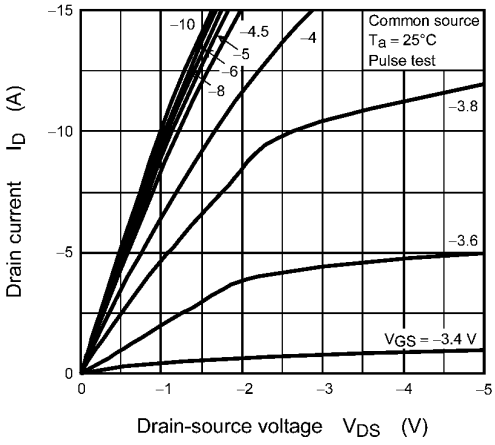


Fig. 8.1 I_D - V_{DS}

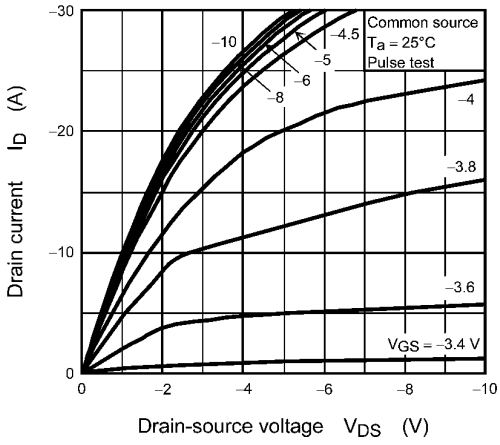


Fig. 8.2 I_D - V_{DS}

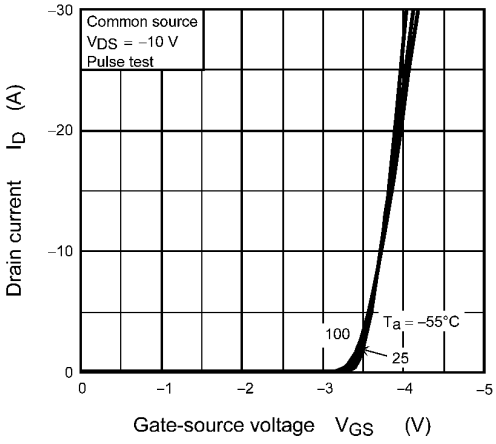


Fig. 8.3 I_D - V_{GS}

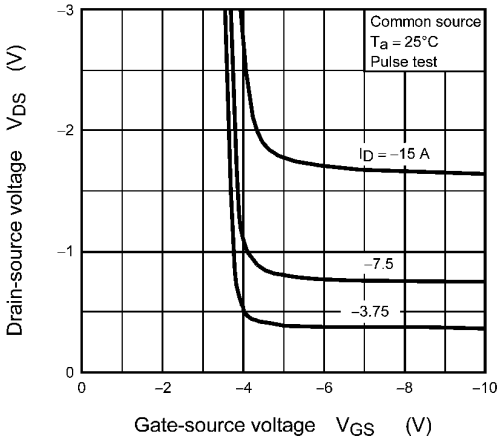


Fig. 8.4 V_{DS} - V_{GS}

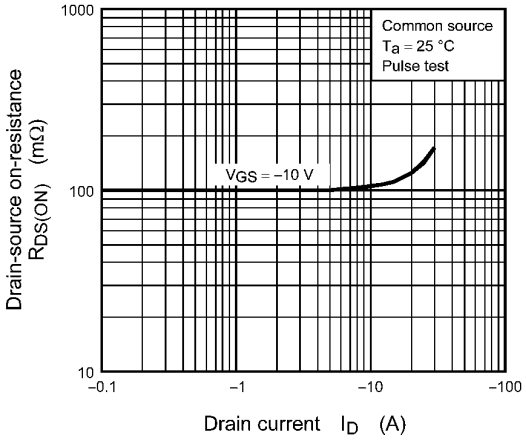


Fig. 8.5 $R_{DS(ON)}$ - I_D

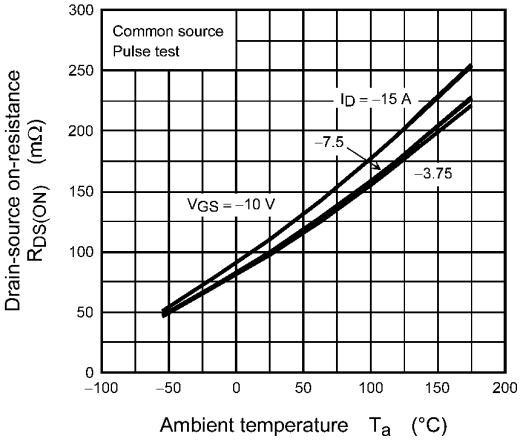


Fig. 8.6 $R_{DS(ON)}$ - T_a

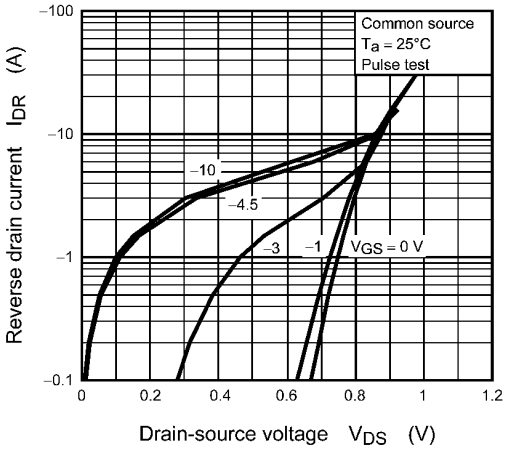


Fig. 8.7 I_{DR} - V_{DS}

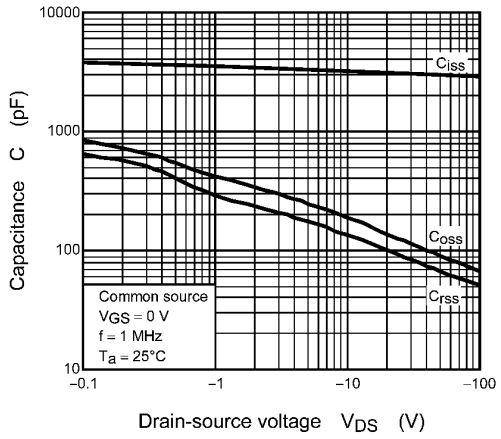


Fig. 8.8 Capacitance - V_{DS}

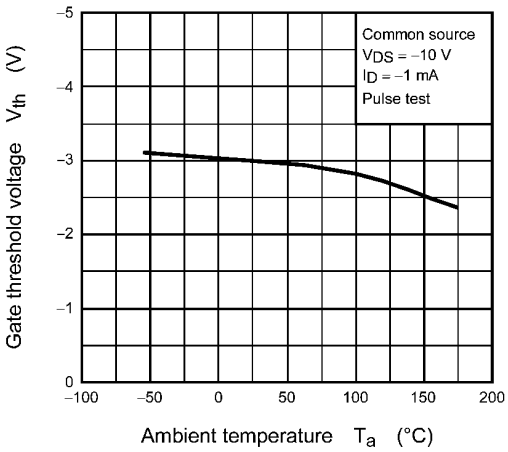


Fig. 8.9 V_{th} - T_a

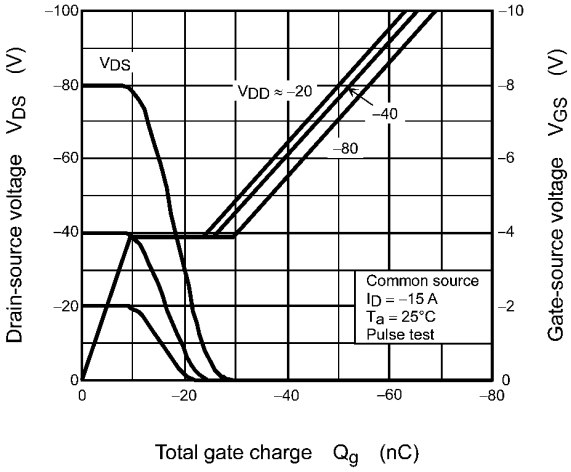


Fig. 8.10 Dynamic Input/Output Characteristics

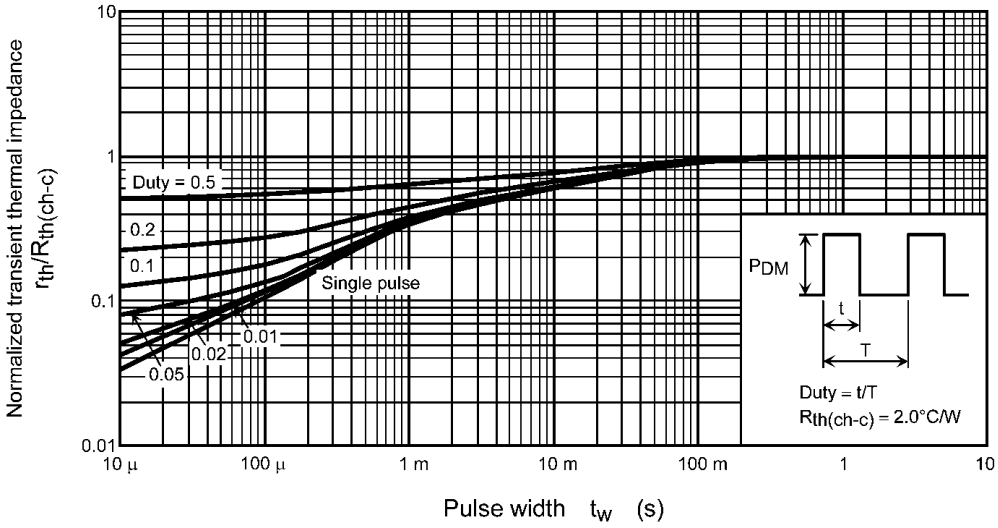


Fig. 8.11 r_{th} - t_w
(Guaranteed Maximum)

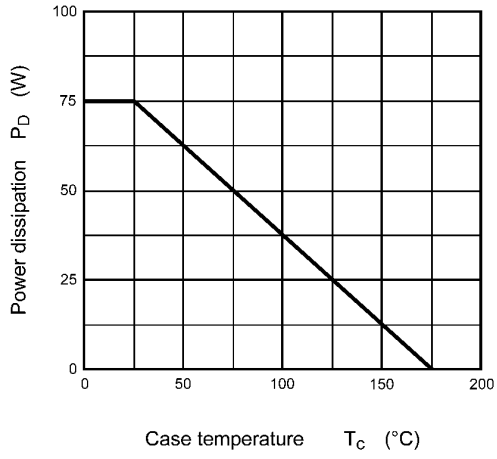


Fig. 8.12 P_D - T_c
(Guaranteed Maximum)

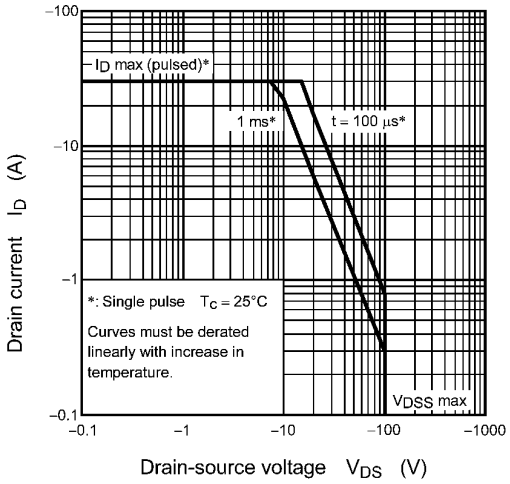
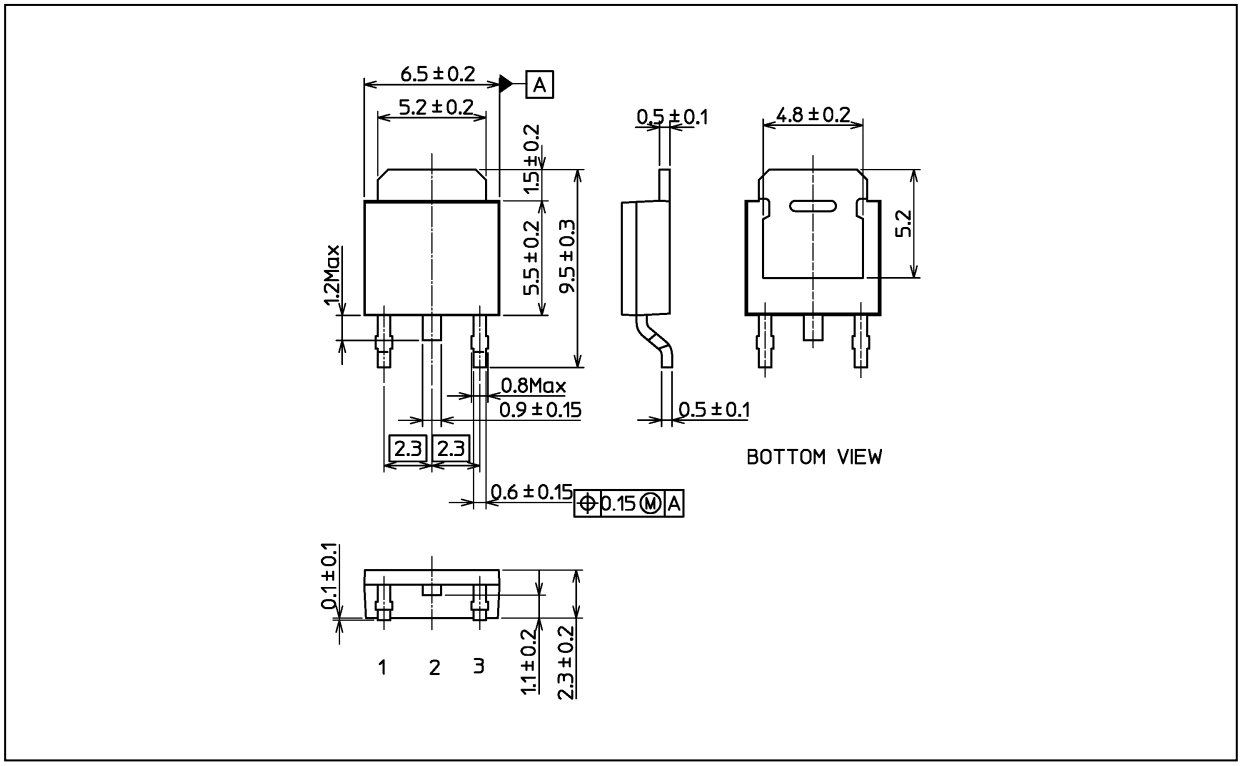


Fig. 8.13 Safe Operating Area
(Guaranteed Maximum)

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 0.36 g (typ.)

Package Name(s)
TOSHIBA: 2-7M1A
Nickname: DPAK+

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